| | Application No. | Applicant(s) |
|--|-------------------|-------------------------------|
| Notice of Allowability | 10/070,172 | BULTMAN, JAN HENDRIK |
| | Examiner | Art Unit |
| | Stanetta D. Isaac | 2812 |
| The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308. | | |
| 1. X This communication is responsive to 09/12/03. | | |
| 2. Magazian The allowed claim(s) is/are 11-23. | | |
| 3. The drawings filed on 12 September 2003 are accepted by the Examiner. | | |
| 4. Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) | | |
| Certified copies of the priority documents have been received. | | |
| Certified copies of the priority documents have been received in Application No | | |
| Copies of the certified copies of the priority documents have been received in this national stage application from the International Bureau (PCT Rule 17.2(a)). | | |
| * Certified copies not received: | | |
| 5. Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application). | | |
| (a) The translation of the foreign language provisional application has been received. | | |
| 6. Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121. | | |
| Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application. THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. | | |
| 7. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient. | | |
| CORRECTED DRAWINGS must be submitted. (a) including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached 1) hereto or 2) to Paper No | | |
| (b) including changes required by the proposed drawing correction filed, which has been approved by the Examiner. | | |
| (c) including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No | | |
| Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. | | |
| DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL. | | |
| Attachment(s) | | |
| 1☐ Notice of References Cited (PTO-892) | | Patent Application (PTO-152) |
| Notice of Draftperson's Patent Drawing Review (PTO-948) Information Disclosure Statements (PTO-1449), Paper No. | | ry (PTO-413), Paper No |
| 7☐ Examiner's Comment Regarding Requirement for Deposit | | ment of Reasons for Allowance |
| of Biological Material | 9☐ Other . | |
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DETAILED ACTION

Response to Arguments

Allowable Subject Matter

- 1. Claims 11-23 are allowed.
- 2. The following is an examiner's statement of reasons for allowance: Applicant's independent claims 11, 20, and 23 are allowed over the prior art of record because none teach or render obvious a method of making a semiconductor device having a substrate with a pattern of highly doped regions and lightly doped regions between the highly doped regions, the method comprising the steps of before the diffusing step, imprinting a diffusion barrier material on the substrate substantially exclusively on the regions that are to be the lightly doped regions.

 Gonsiorawski US Patent 4,152,824 discloses the semiconductor method however, fails the step of having two separate layers, a continuous layer of doping material and a diffusion barrier material layer. In the Gonisorawski reference it teaches a doped silicon dioxide layer verses the claimed invention where a barrier layer consisting of either silicon nitride (Si₃N₄), silicon dioxide layer (SiO₂), or titanium oxide (TiO₂) is formed and a separate doping material for example an organic molecule.
- All dependent claims are rendered allowable.
- 4. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

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Any inquiry concerning this communication or earlier communications from the
examiner should be directed to Stanctta D. Isaac whose telephone number is 703-308-5871. The
examiner can normally be reached on Monday-Friday 7:30am -5:30pm.

- 6. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Nebling can be reached on 703-308-3325. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.
- Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

Stanetta Isaac Patent Examinor October 3, 2003 Jully